NSN 5962-01-253-0170

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-253-0170 **Body Length:** 1.290 inches **Body Width:** 0.610 inches **Body Height:** 0.150 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Radar set an/sps-4 (v) 5 **Features Provided:** Schottky and programmable and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Shelf Life: N/a

24 printed circuit

Terminal Type And Quantity:

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Demilitarization:

Yes - demil/mli

Fiig:

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